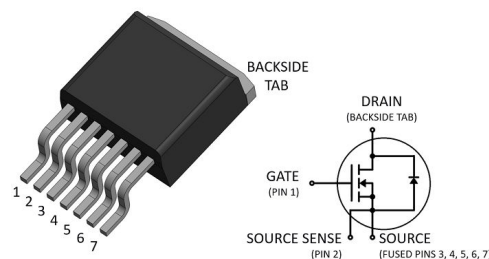# MSC060SMA070SA

700 V 60 mΩ SiC N-Channel Power MOSFET

Product Overview

The silicon carbide (SiC) power MOSFET product line from Microchip increases the performance over silicon MOSFET and silicon IGBT solutions while lowering the total cost of ownership for high-voltage applications. The MSC060SMA070SA device is a 700 V, 60 mΩ SiC MOSFET in a TO-263 7-lead package with a source sense.

Features

The following are key features of the MSC060SMA070SA device:

- Low capacitances and low gate charge
- Fast switching speed due to low internal gate resistance (ESR)
- Stable operation at high junction temperature, $T_{J(max)}$ = 175 °C
- Fast and reliable body diode
- Superior avalanche ruggedness
- RoHS compliant

Benefits

The following are benefits of the MSC060SMA070SA device:

- High efficiency to enable lighter, more compact system
- Simple to drive and easy to parallel
- Improved thermal capabilities and lower switching losses
- Eliminates the need for external freewheeling diode
- Lower system cost of ownership

Applications

The MSC060SMA070SA device is designed for the following applications:

- PV inverter, converter, and industrial motor drives
- Smart grid transmission and distribution
- Induction heating and welding
- H/EV powertrain and EV charger
- Power supply and distribution

1. Device Specifications

This section shows the specifications of the MSC060SMA070SA device.

1.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings of the MSC060SMA070SA device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain source voltage	700	V
I_D	Continuous drain current at T_C = 25 °C	48	A
	Continuous drain current at T_C = 100 °C	34	
I_{DM}	Pulsed drain current[1]	100	
V_{GS}	Gate-source voltage	23 to –10	V
P_D	Total power dissipation at T_C = 25 °C	208	W
	Linear derating factor	1.39	W/°C

Note:
1. Repetitive rating: pulse width and case temperature limited by maximum junction temperature.

The following table shows the thermal and mechanical characteristics of the MSC060SMA070SA device.

Table 1-2. Thermal and Mechanical Characteristics

Symbol	Characteristic/Test Conditions	Min	Typ	Max	Unit
$R_{\theta JC}$	Junction-to-case thermal resistance		0.48	0.72	°C/W
T_J	Operating junction temperature	–55		175	°C
T_{STG}	Storage temperature	–55		150	°C
	Reflow temperature			260	°C
Wt	Package weight		0.05		oz
			1.42		g

1.2 Electrical Performance

The following table shows the static characteristics of the MSC060SMA070SA device. T_J = 25 °C unless otherwise specified.

Table 1-3. Static Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	V_{GS} = 0 V, I_D = 100 µA	700			V
$R_{DS(on)}$	Drain-source on resistance[1]	V_{GS} = 20 V, I_D = 20 A		60	75	mΩ
$V_{GS(th)}$	Gate-source threshold voltage	V_{GS} = V_{DS}, I_D = 1 mA	1.9	2.4		V

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
..........continued						
I_{DSS}	Zero gate voltage drain current	V_{DS} = 700 V, V_{GS} = 0 V			100	µA
		V_{DS} = 700 V, V_{GS} = 0 V, T_J = 125 °C			500	
I_{GSS}	Gate-source leakage current	V_{GS} = 20 V/–10 V			±100	nA

Note:

1.   Pulse test: pulse width < 380 µs, duty cycle < 2%.

The following table shows the dynamic characteristics of the MSC060SMA070SA device. T_J = 25 °C unless otherwise specified.

Table 1-4. Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input capacitance	V_{GS} = 0 V, V_{DD} = 700 V, V_{AC} = 25 mV, f = 1 MHz		1175		pF
C_{rss}	Reverse transfer capacitance			8		
C_{oss}	Output capacitance			130		
Q_g	Total gate charge	V_{GS} = –5 V/20 V, V_{DD} = 470 V, I_D = 20 A		56		nC
Q_{gs}	Gate-source charge			15		
Q_{gd}	Gate-drain charge			9		
$t_{d(on)}$	Turn-on delay time	V_{DD} = 470 V, V_{GS} = –5 V/20 V, I_D = 20 A, $R_{g(ext)}$ = 8 Ω, Freewheeling diode = MSC060SMA070SA (V_{GS} = –5 V); reference Fig. 1-16		14		ns
t_r	Voltage rise time			11		
$t_{d(off)}$	Turn-off delay time			22		
t_f	Voltage fall time			9		
E_{on}	Turn-on switching energy			125		µJ
E_{off}	Turn-off switching energy			19		
ESR	Gate equivalent series resistance	f = 1 MHz, 25 mV, drain short		2.6		Ω
SCWT	Short circuit withstand time	V_{DS} = 560 V, V_{GS} = 20 V		3		µs
E_{AS}	Avalanche energy, single pulse	V_{DS} = 150 V, I_D = 20 A		1150		mJ

The following table shows the body diode characteristics of the MSC060SMA070SA device. T_J = 25 °C unless otherwise specified.

Table 1-5. Body Diode Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_{SD}	Diode forward voltage	I_{SD} = 20 A, V_{GS} = 0 V		4.0		V
		I_{SD} = 20 A, V_{GS} = –5 V		4.2		

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
..........continued						
t_{rr}	Reverse recovery time	I_{SD} = 20 A, V_{GS} = –5 V, V_{DD} = 470 V, dl/dt = –10000 A/μs, Drive Rg = 8 Ω		11		ns
Q_{rr}	Reverse recovery charge			404		nC
I_{RRM}	Reverse recovery current			64		A

1.3   Typical Performance Curves

This section shows the typical performance curves of the MSC060SMA070SA device.

Figure 1-1. Drain Current vs. V_{DS} at T_J

Figure 1-2. Drain Current vs. V_{DS} at V_{GS}

Figure 1-3. Drain Current vs. V_{DS} at V_{GS}

Figure 1-4. Drain Current vs. V_{DS} at V_{GS}
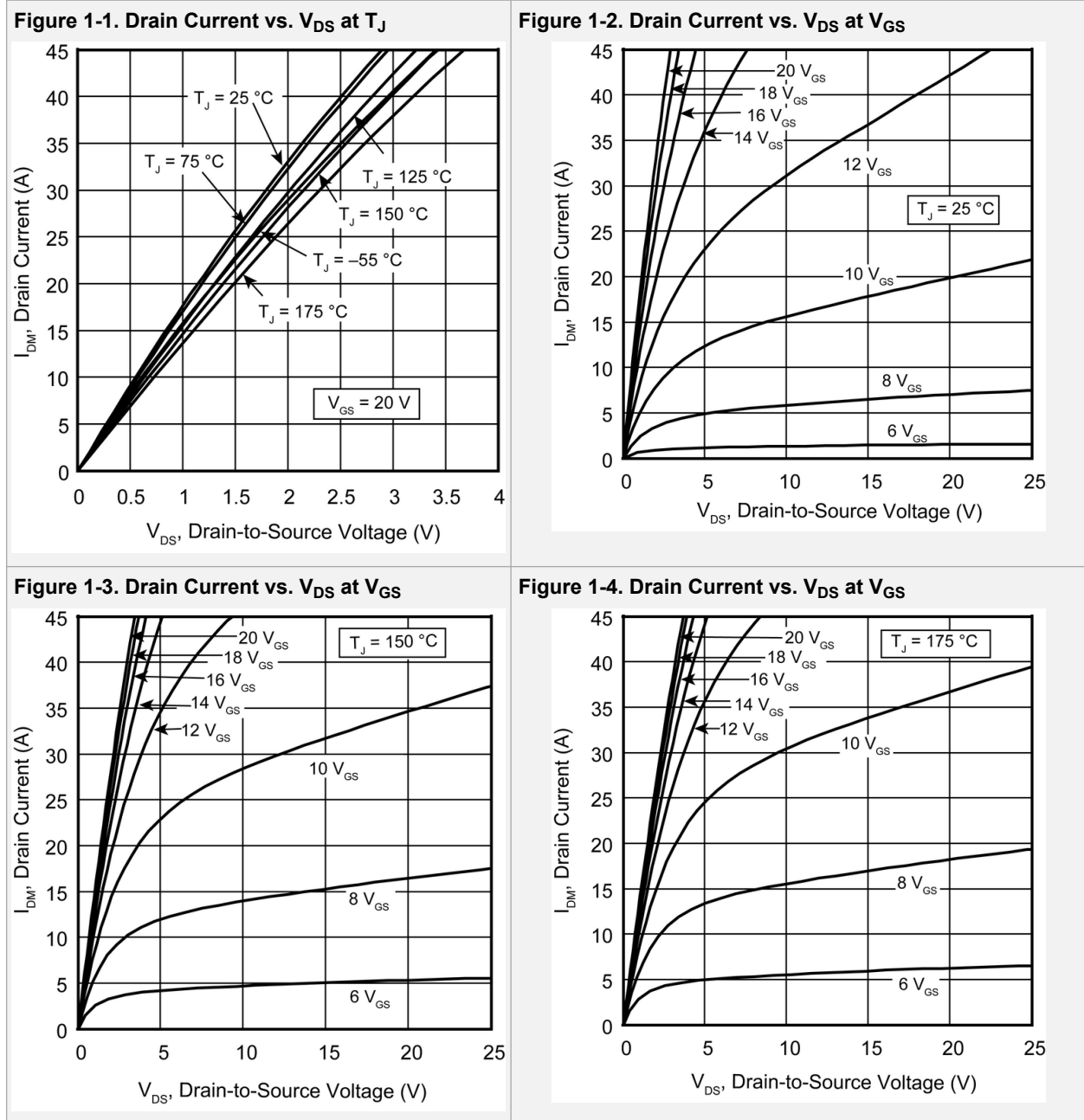
Figure 1-5. $R_{DS(on)}$ vs. Junction Temperature
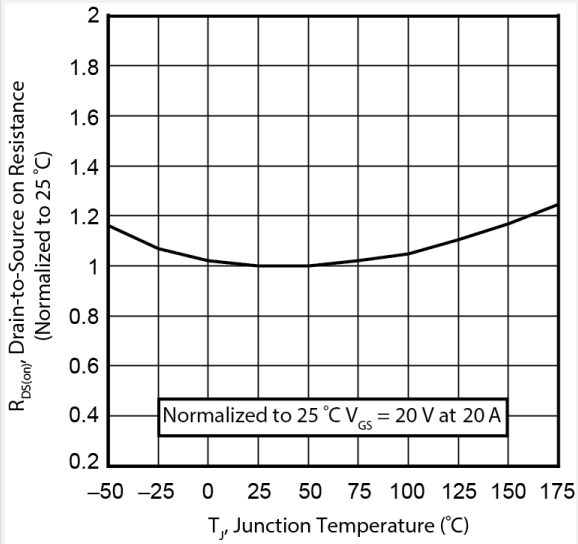
Figure 1-6. Gate Charge Characteristics

I_{GS} = 1 mA
I_{DS} = 20 A
V_{DS} = 470 V
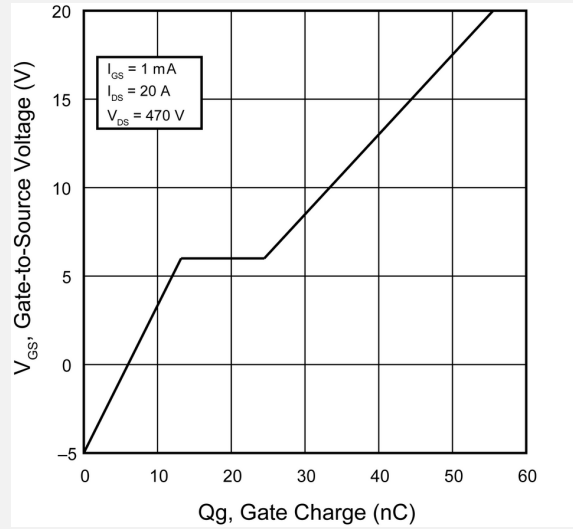
Figure 1-7. Capacitance vs. Drain-to-Source Voltage
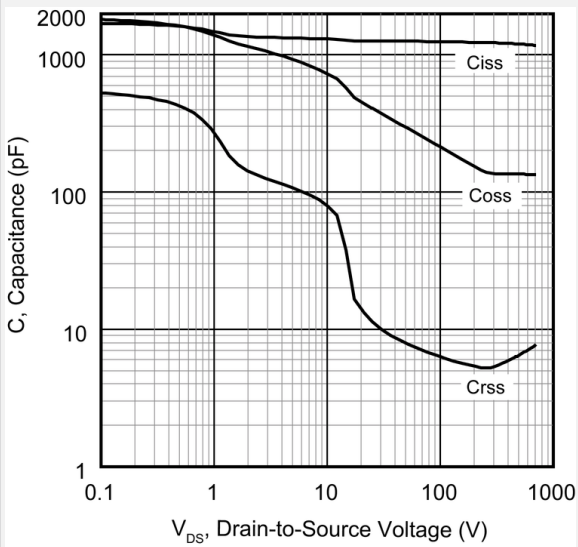
Figure 1-8. I_D vs. V_{DS} 3rd Quadrant Conduction

T_J = 25 °C
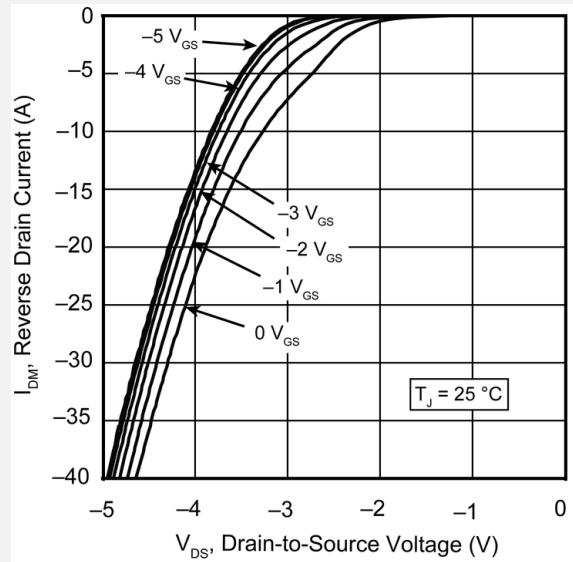
Figure 1-9. I_D vs. V_{DS} 3rd Quadrant Conduction
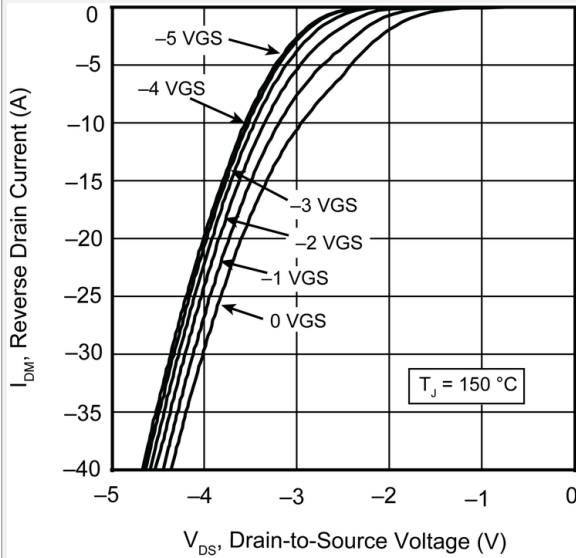
Figure 1-10. Switching Energy vs. V_{DS} & I_D
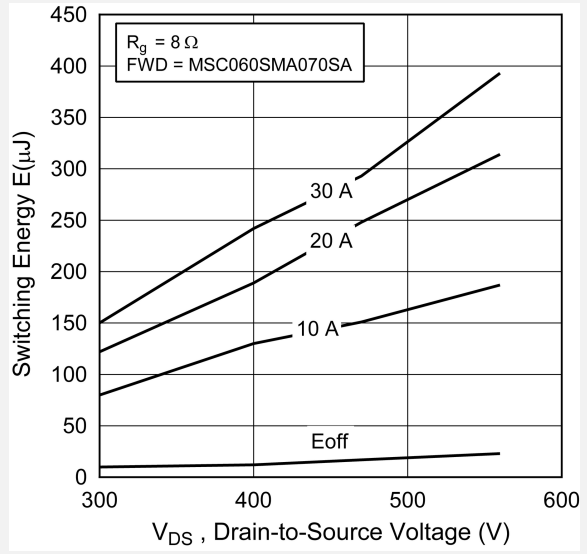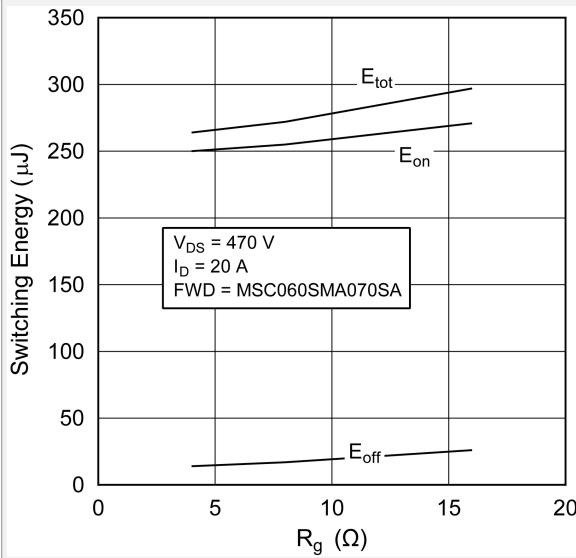

Figure 1-11. Switching Energy vs. R_g

Figure 1-12. Switching Energy vs. Temperature
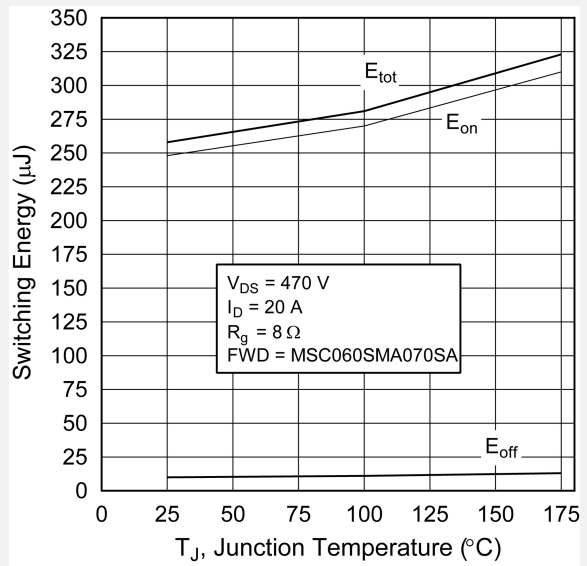
Figure 1-13. Threshold Voltage vs. Junction Temp.
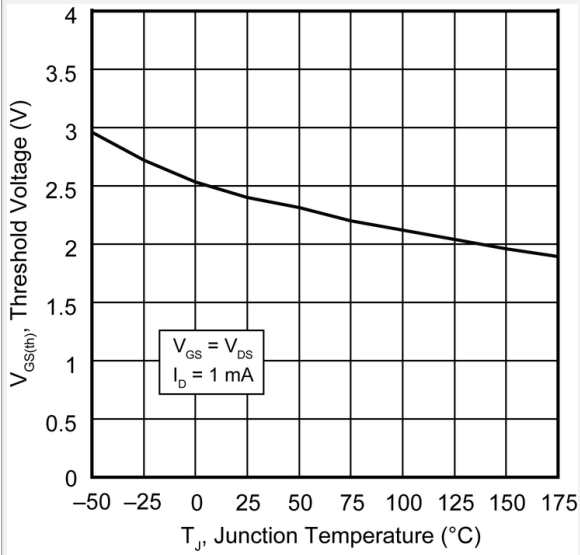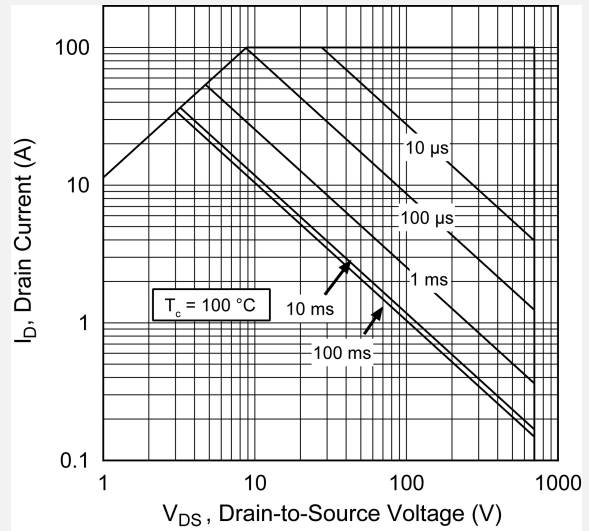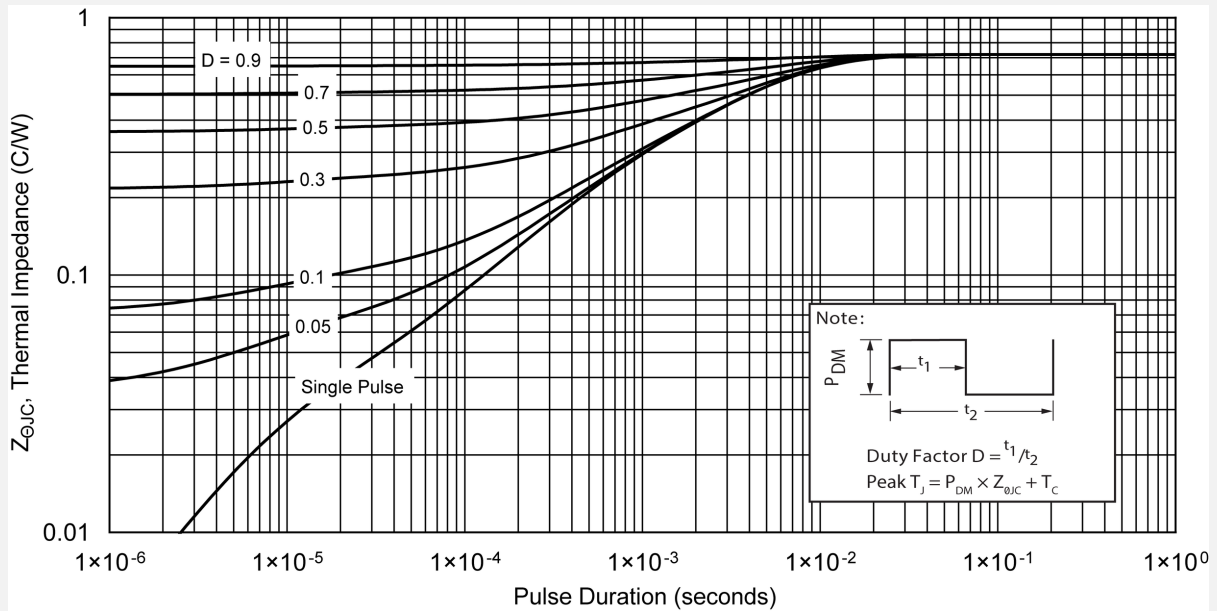

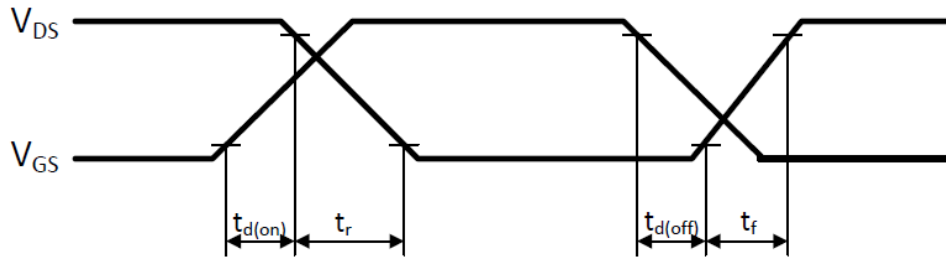**Figure 1-14. Forward Safe Operating Area**

Figure 1-15. Maximum Transient Thermal Impedance

The following figure shows the switching waveform diagram of the MSC060SMA070SA device.

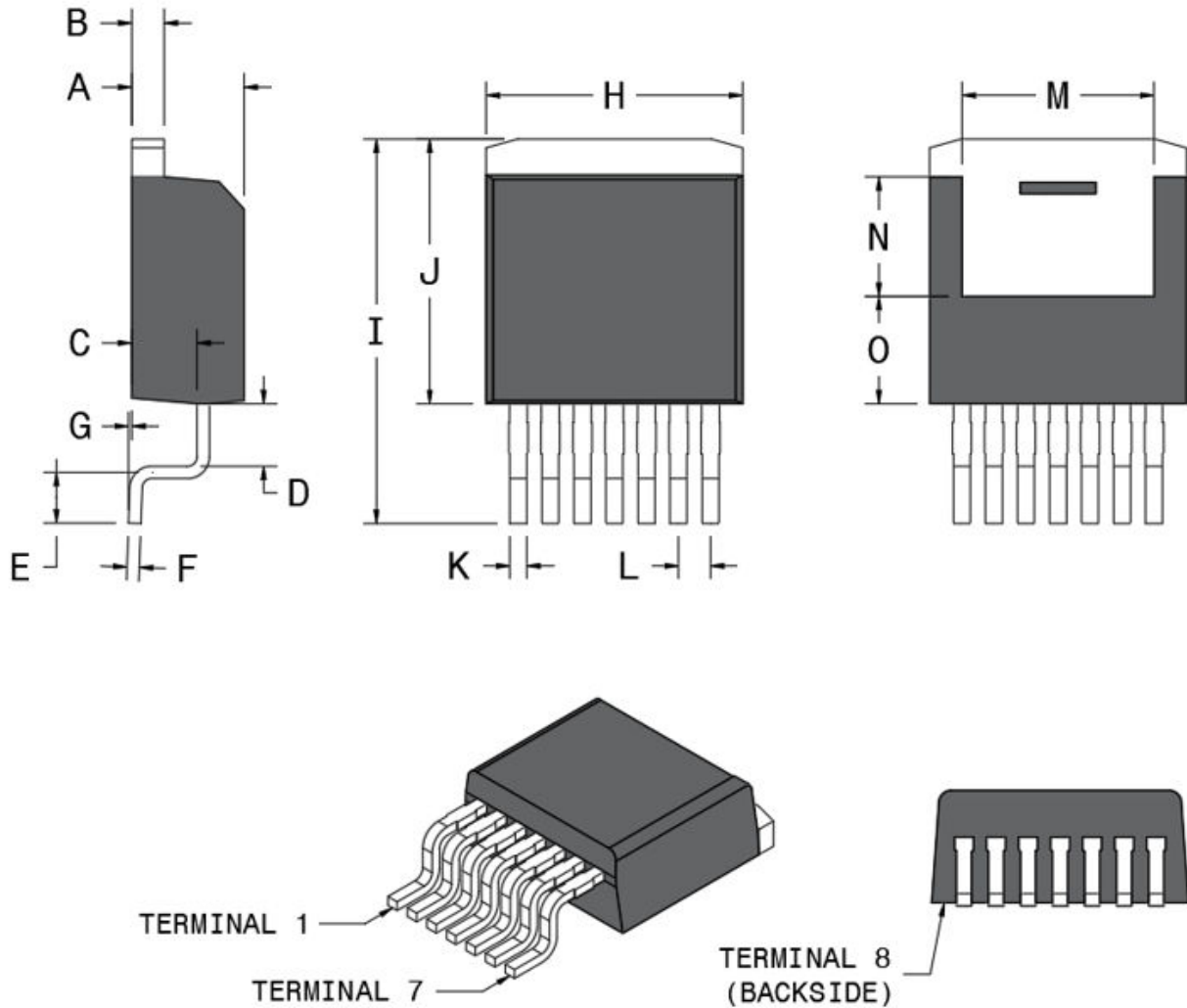**Figure 1-16. Switching Waveform**

2.   Package Specification

This section shows the package specification of the MSC060SMA070SA device.

2.1   Package Outline Drawing

The following figure illustrates the TO-263 7-lead package outline of the MSC060SMA070SA device.

Figure 2-1. Package Outline Drawing

The following table shows the TO-263 7-lead dimensions and should be used in conjunction with the package outline drawing.

Table 2-1. TO-263 Dimensions

Symbol	Min (mm)	Max (mm)	Min (in.)	Max (in.)
A	4.30	4.57	0.169	0.180
B	1.17	1.40	0.046	0.055
C	2.50	2.70	0.098	0.106

..........continued

Symbol	Min (mm)	Max (mm)	Min (in.)	Max (in.)
D	2.85	2.95	0.112	0.116
E	2.32	2.70	0.091	0.106
F	0.33	0.65	0.013	0.026
G	0.00	0.25	0.00	0.010
H	10.13	10.23	0.399	0.403
I	15.04	17.12	0.592	0.674
J	10.19	10.80	0.401	0.425
K	0.50	0.70	0.020	0.028
L	1.27 BSC		0.050 BSC	
M	6.78	7.67	0.267	0.302
N	4.66	4.81	0.183	0.189
O	4.20	4.30	0.165	0.169
Terminal 1	Gate			
Terminal 2	Source sense			
Terminal 3	Source			
Terminal 4	Source			
Terminal 5	Source			
Terminal 6	Source			
Terminal 7	Source			
Terminal 8	Drain			

3.   Revision History

Table 3-1. Revision History

Revision	Date	Description
A	03/2022	Document created.

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